



Features

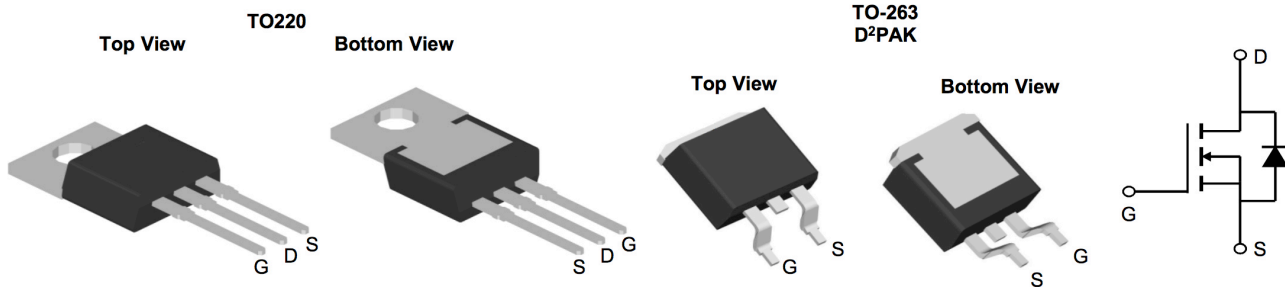
- 150V/200A
 $R_{DS(on)} = 6.3m\Omega(Typ.)@V_{GS}=10V$
- Advanced HEFE[®] Technology
- Ultra Low On-Resistance
- Excellent $g_m \times R_{DS(on)}$ Product
- 100% avalanche tested
- 175°C Operating Temperature
- Lead Free and Green Devices Available (RoHS Compliant)

Applications

- Motor Drive
- Uninterruptible Power Supply
- DC/DC converter
- General Purpose Application



Pin Configurations



Common Ratings ($T_C=25^\circ C$ Unless Otherwise Noted)

| | | | | |
|---------------------------------------|--|-------------------|--------------|---|
| V_{DSS} | Drain-Source Voltage | 150 | V | |
| V_{GSS} | Gate-Source Voltage | ± 20 | | |
| T_J | Maximum Junction Temperature | 175 | $^\circ C$ | |
| T_{STG} | Storage Temperature Range | -55 to 175 | $^\circ C$ | |
| I_S | Diode Continuous Forward Current | $T_C=25^\circ C$ | 200 | A |
| Mounted on Large Heat Sink | | | | |
| $I_{DP}^{(1)}$ | 300 μs Pulse Drain Current Tested | $T_C=25^\circ C$ | 600 | A |
| $I_D^{(2)}$ | Continuous Drain Current($V_{GS}=10V$) | $T_C=25^\circ C$ | 200 | A |
| | | $T_C=100^\circ C$ | 156 | |
| P_D | Maximum Power Dissipation | $T_C=25^\circ C$ | 394 | W |
| | | $T_C=100^\circ C$ | 197 | |
| $R_{\theta JC}$ | Thermal Resistance-Junction to Case | 0.38 | $^\circ C/W$ | |
| $R_{\theta JA}$ | Thermal Resistance-Junction to Ambient | 62.5 | $^\circ C/W$ | |
| Drain-Source Avalanche Ratings | | | | |
| $E_{AS}^{(3)}$ | Avalanche Energy, Single Pulsed | 702 | mJ | |

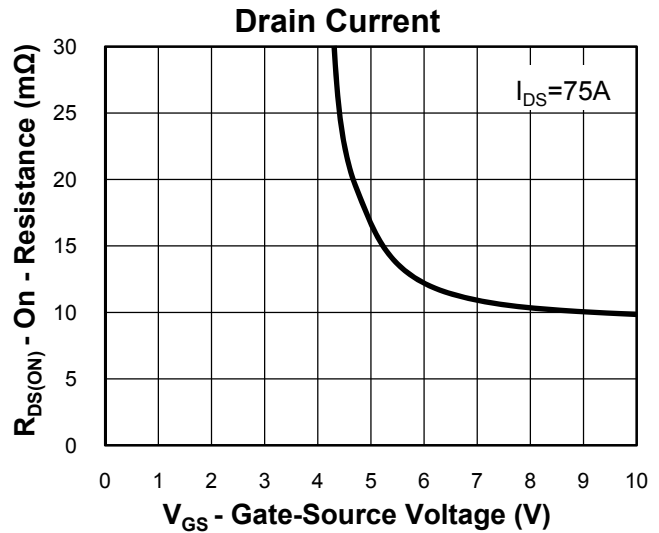
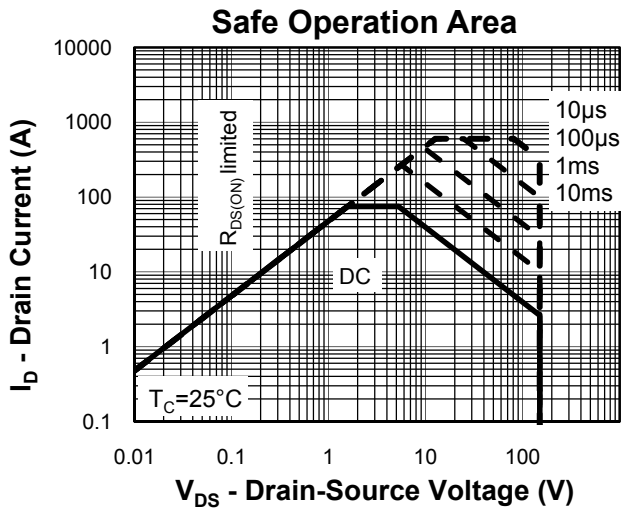
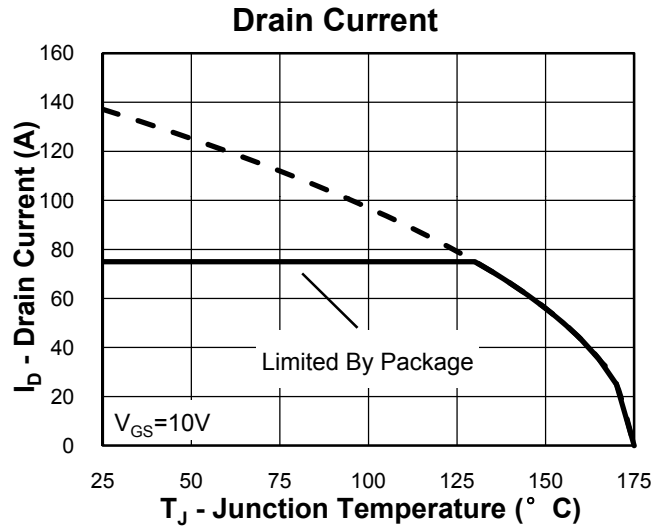
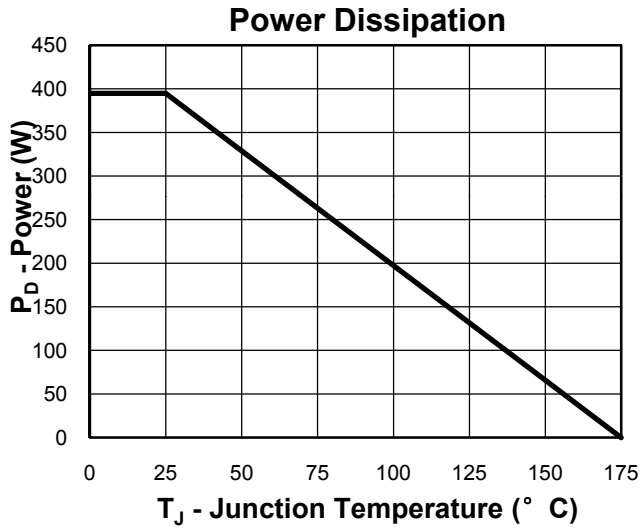
Electrical Characteristics ($T_C=25^\circ\text{C}$ Unless Otherwise Noted)

| Symbol | Parameter | Test Condition | RU1Z150S | | | Unit |
|---|----------------------------------|--|---|------|-----------|------------|
| | | | Min. | Typ. | Max. | |
| Static Characteristics | | | | | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{GS}=0V, I_{DS}=250\mu A$ | 150 | | | V |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS}=150V, V_{GS}=0V$ | | | 1 | μA |
| | | $T_J=125^\circ C$ | | | 30 | |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS}=V_{GS}, I_{DS}=250\mu A$ | 2.5 | | 4.5 | V |
| I_{GSS} | Gate Leakage Current | $V_{GS}=\pm 25V, V_{DS}=0V$ | | | ± 100 | nA |
| $R_{DS(ON)}^{(4)}$ | Drain-Source On-state Resistance | $V_{GS}=10V, I_{DS}=75A$ | | 6.3 | 7.3 | m Ω |
| Diode Characteristics | | | | | | |
| $V_{SD}^{(4)}$ | Diode Forward Voltage | $I_{SD}=75A, V_{GS}=0V$ | | | 1.2 | V |
| t_{rr} | Reverse Recovery Time | $I_{SD}=75A, di_{SD}/dt=100A/\mu s$ | | 55 | | ns |
| Q_{rr} | Reverse Recovery Charge | | | 105 | | nC |
| Dynamic Characteristics ⁽⁵⁾ | | | | | | |
| R_G | Gate Resistance | $V_{GS}=0V, V_{DS}=0V, F=1MHz$ | | 1.5 | | Ω |
| C_{iss} | Input Capacitance | $V_{GS}=0V, V_{DS}=50V, \text{Frequency}=1.0MHz$ | | 5140 | | pF |
| C_{oss} | Output Capacitance | | | 409 | | |
| C_{riss} | Reverse Transfer Capacitance | | | 10 | | |
| $t_{d(ON)}$ | Turn-on Delay Time | | $V_{DD}=75V, I_{DS}=75A, V_{GEN}=10V, R_G=25\Omega$ | | 37 | |
| t_r | Turn-on Rise Time | | | 123 | | |
| $t_{d(OFF)}$ | Turn-off Delay Time | | | 190 | | |
| t_f | Turn-off Fall Time | | | 67 | | |
| Gate Charge Characteristics ⁽⁵⁾ | | | | | | |
| Q_g | Total Gate Charge | $V_{DS}=120V, V_{GS}=10V, I_{DS}=75A$ | | 247 | | nC |
| Q_{gs} | Gate-Source Charge | | | 19 | | |
| Q_{gd} | Gate-Drain Charge | | | 168 | | |

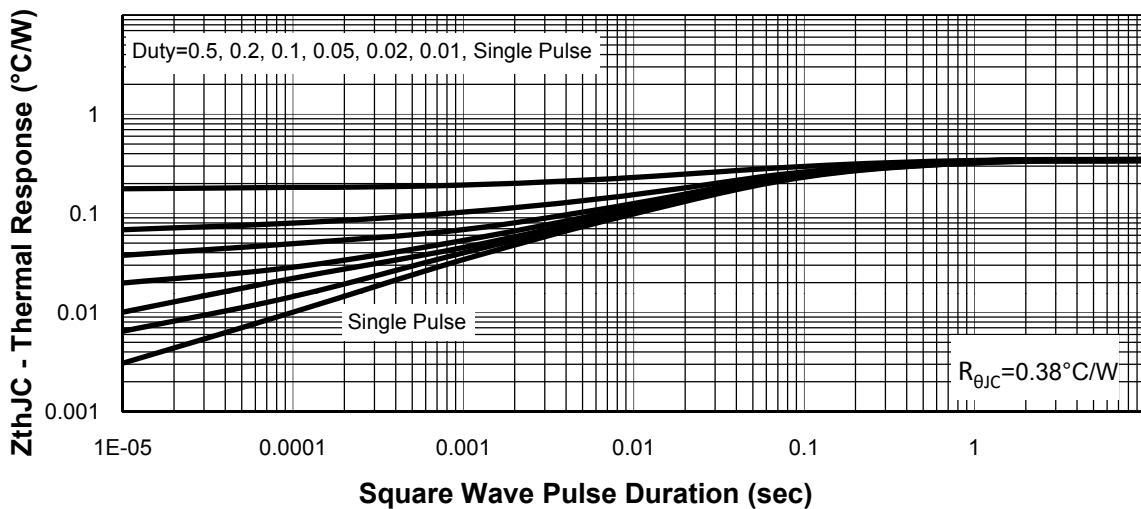
- Notes:
- ① Pulse width limited by safe operating area.
 - ② Calculated continuous current based on maximum allowable junction temperature. The package limitation current is 75A.
 - ③ Limited by $T_{Jmax}, I_{AS}=53A, V_{DD}=48V, R_G=47\Omega$, Starting $T_J=25^\circ C$.
 - ④ Pulse test; Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
 - ⑤ Guaranteed by design, not subject to production testing.

| Device | Marking | Package | Packaging | Quantity | Reel Size | Tape width |
|--------------|--------------|---------|-----------|----------|-----------|------------|
| XPX150N200TU | XPX150N200TU | TO263 | Tube | 50 | - | - |

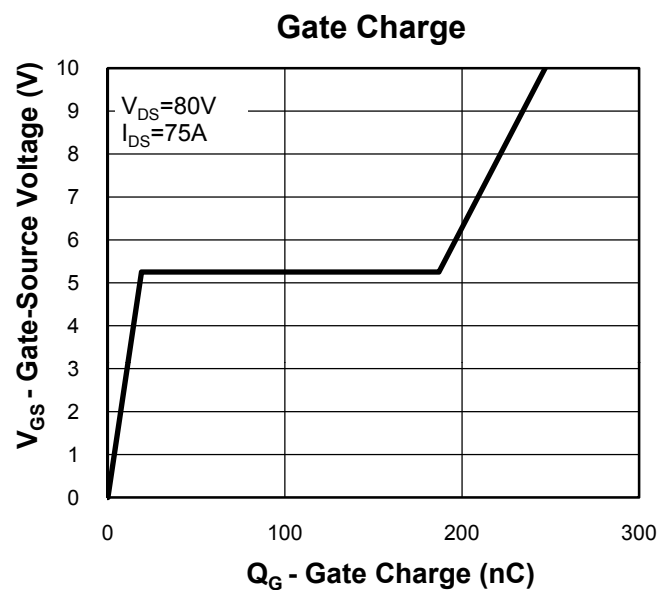
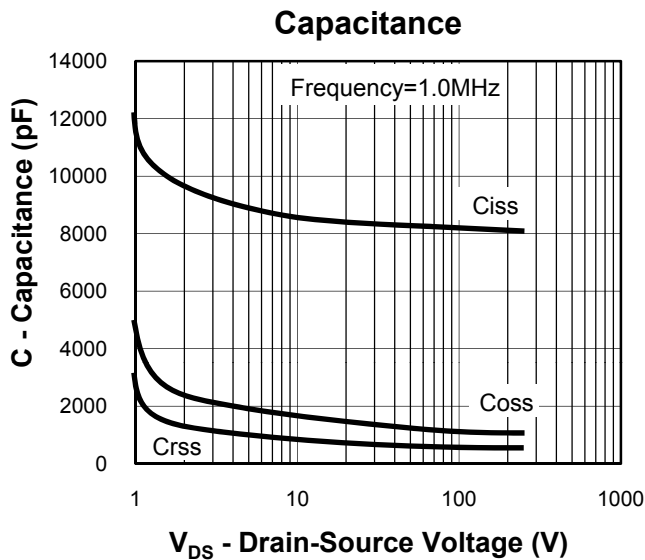
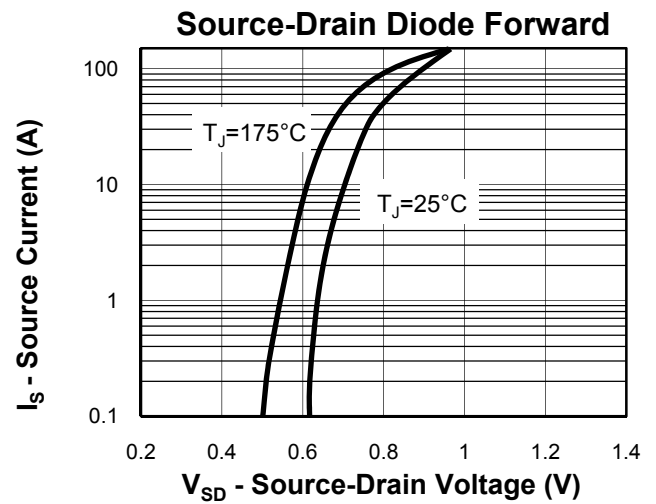
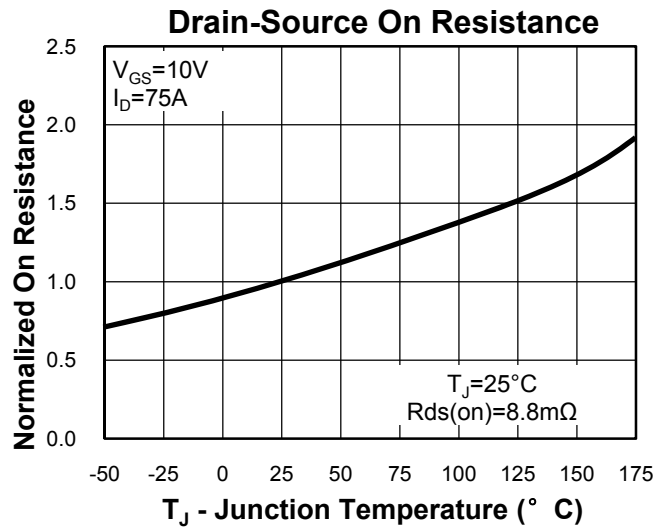
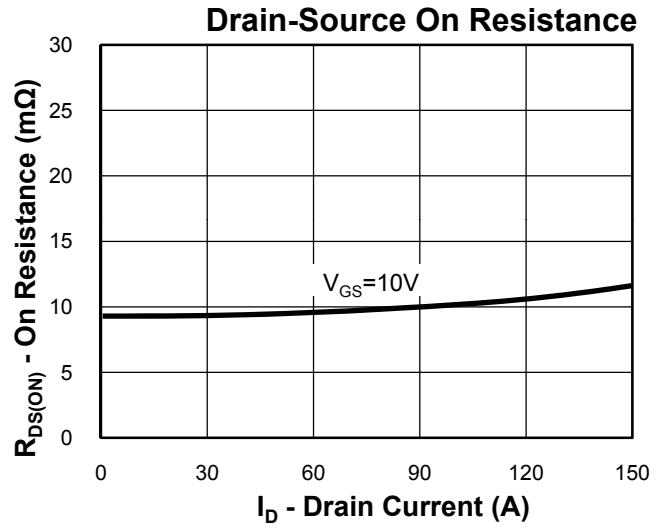
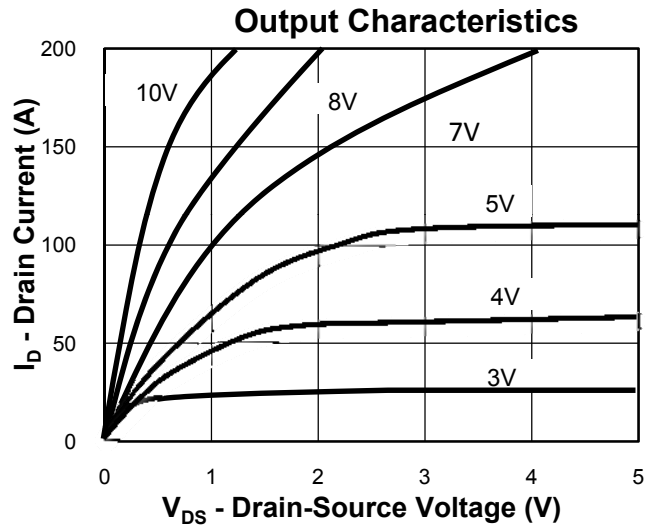
Typical Characteristics



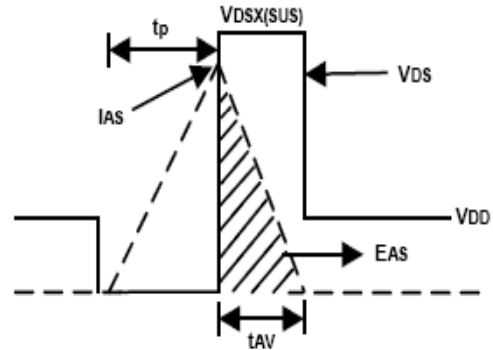
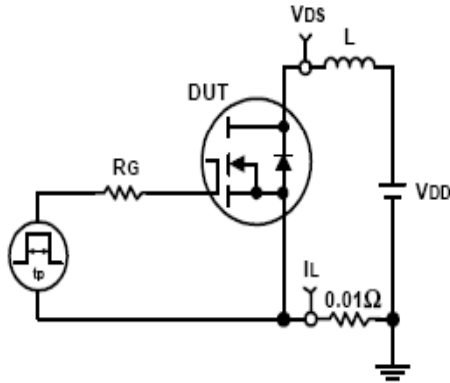
Thermal Transient Impedance



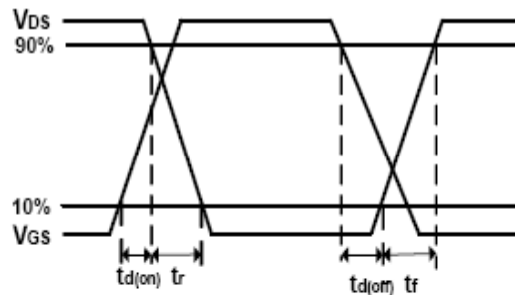
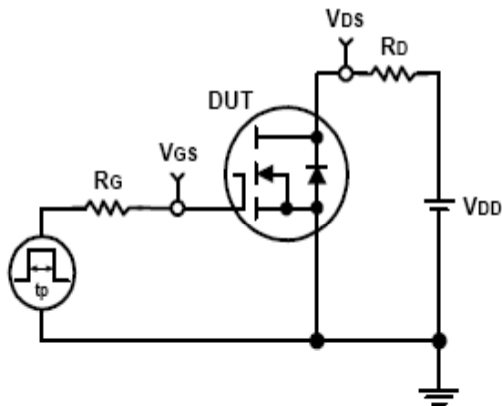
Typical Characteristics

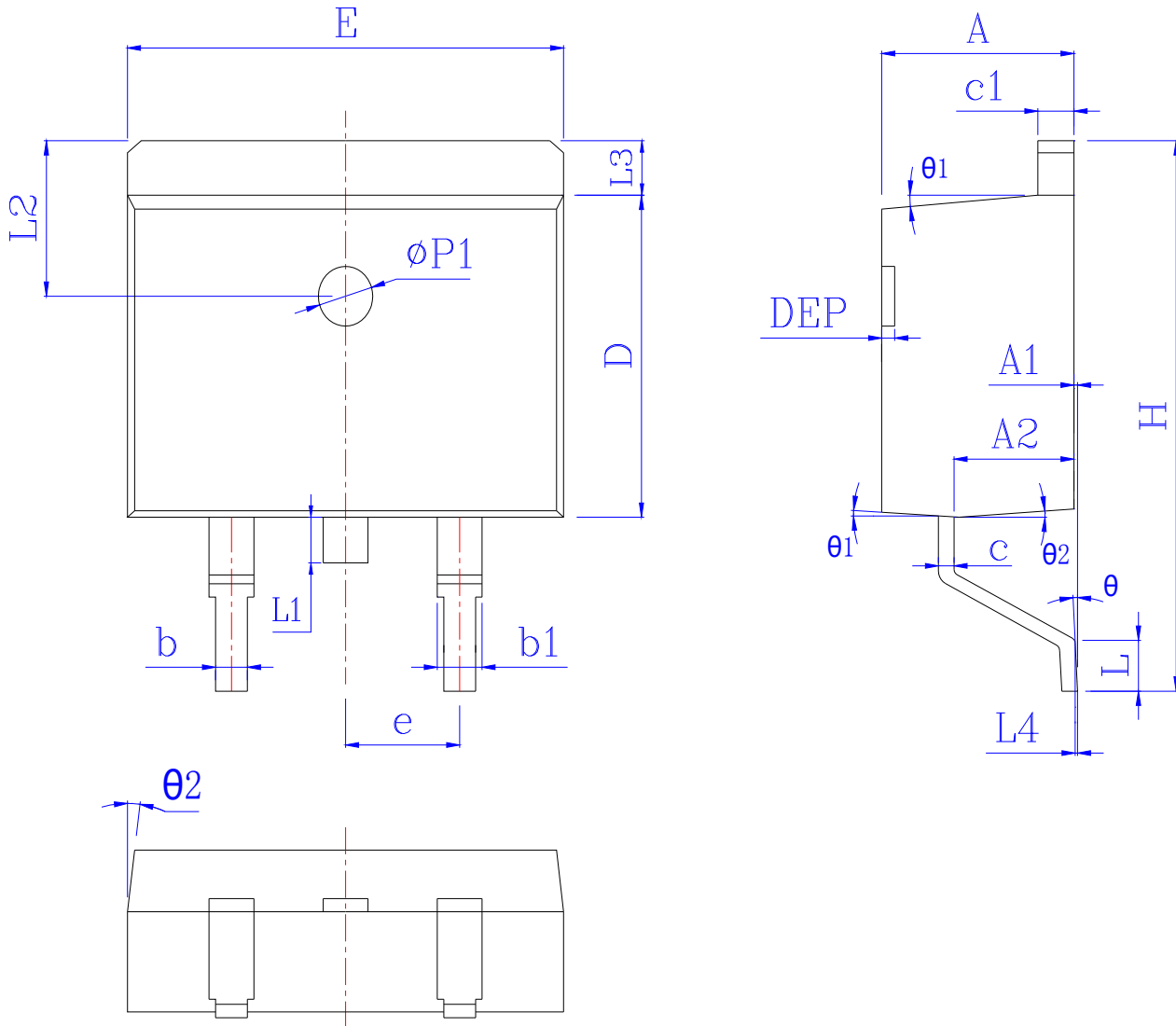


Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms

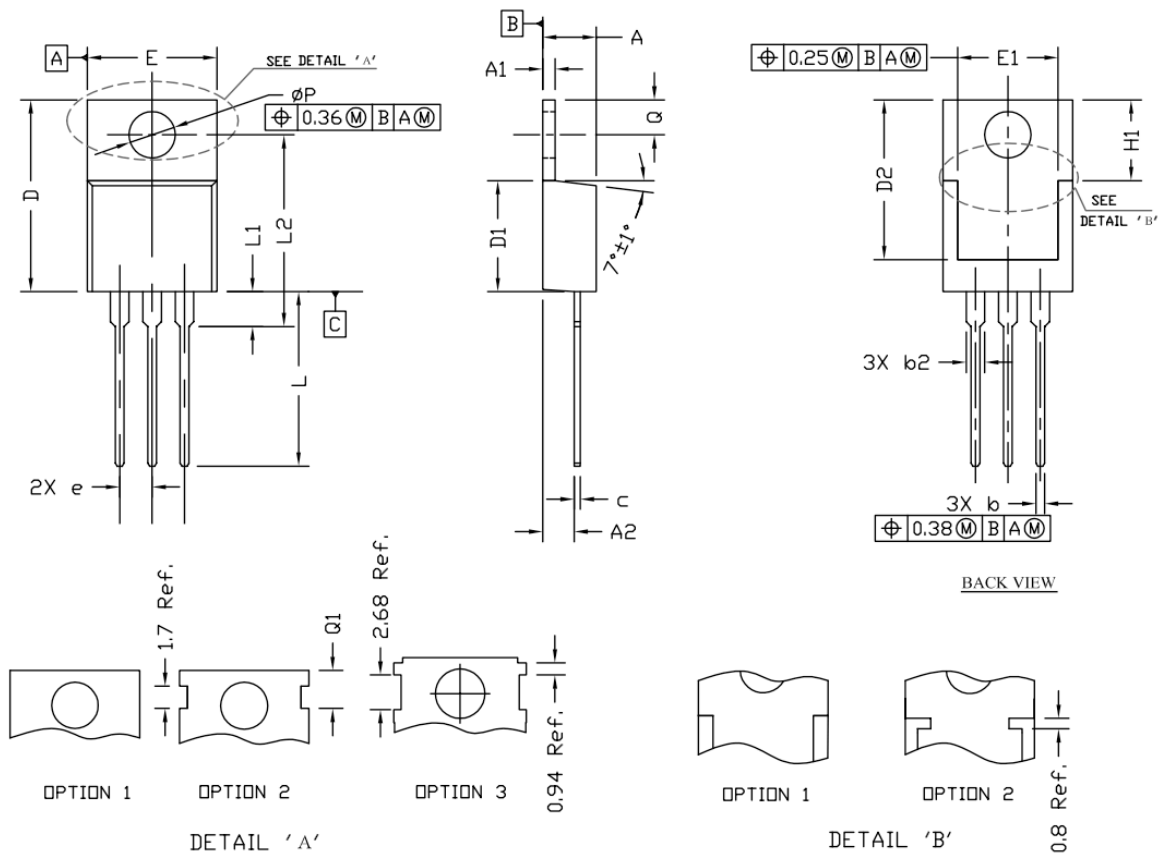


Package Information
TO263


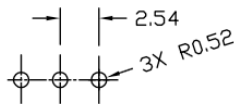
| SYMBOL | MM | | | INCH | | | SYMBOL | MM | | | INCH | | |
|--------|---------|-------|-------|----------|-------|-------|-----------|----------|------|------|-----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX | | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.40 | 4.55 | 4.72 | 0.173 | 0.179 | 0.186 | L | 1.94 | 2.30 | 2.60 | 0.076 | 0.091 | 0.102 |
| A1 | 0.00 | 0.10 | 0.25 | 0.000 | 0.005 | 0.010 | L3 | 1.17 | 1.29 | 1.40 | 0.046 | 0.051 | 0.055 |
| A2 | 2.59 | 2.69 | 2.79 | 0.102 | 0.106 | 0.110 | L1 | * | * | 1.70 | * | * | 0.067 |
| b | 0.76 | * | 0.90 | 0.030 | * | 0.035 | L4 | 0.25 BSC | | | 0.01 BSC | | |
| b1 | 1.22 | * | 1.36 | 0.048 | * | 0.054 | L2 | 2.50 REF | | | 0.098 REF | | |
| c | 0.33 | * | 0.47 | 0.013 | * | 0.019 | θ | 0° | * | 8° | 0° | * | 8° |
| c1 | 1.22 | * | 1.32 | 0.048 | * | 0.052 | $\theta1$ | 5° | 7° | 9° | 5° | 7° | 9° |
| D | 8.60 | * | 9.29 | 0.339 | * | 0.366 | $\theta2$ | 1° | 3° | 5° | 1° | 3° | 5° |
| E | 9.95 | * | 10.26 | 0.392 | * | 0.404 | DEP | 0.05 | 0.10 | 0.20 | 0.002 | 0.004 | 0.008 |
| e | 2.54BSC | | | 0.100BSC | | | $\Phi p1$ | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 |
| H | 14.70 | 15.10 | 15.79 | 0.579 | 0.594 | 0.622 | | | | | | | |

● Package Information

TO220 PACKAGE OUTLINE



RECOMMENDATION OF HOLE PATTERN



UNIT: mm

NOTE

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH SHOULD BE LESS THAN 6 MIL.
2. TOLERANCE 0.100 MILLIMETERS UNLESS OTHERWISE SPECIFIED.
3. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.

| SYMBOLS | DIMENSIONS IN MILLIMETERS | | | DIMENSIONS IN INCHES | | |
|---------|---------------------------|-------|-------|----------------------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.30 | 4.45 | 4.72 | 0.169 | 0.175 | 0.186 |
| A1 | 1.15 | 1.27 | 1.40 | 0.045 | 0.050 | 0.055 |
| A2 | 2.20 | 2.67 | 2.90 | 0.087 | 0.105 | 0.114 |
| b | 0.69 | 0.81 | 0.95 | 0.027 | 0.032 | 0.037 |
| b2 | 1.17 | 1.37 | 1.45 | 0.046 | 0.050 | 0.068 |
| c | 0.36 | 0.38 | 0.60 | 0.014 | 0.015 | 0.024 |
| D | 14.50 | 15.44 | 15.80 | 0.571 | 0.608 | 0.622 |
| D1 | 8.59 | 9.14 | 9.65 | 0.338 | 0.360 | 0.380 |
| D2 | 11.43 | 11.73 | 12.48 | 0.450 | 0.462 | 0.491 |
| e | 2.54 BSC | | | 0.100 BSC | | |
| E | 9.66 | 10.03 | 10.54 | 0.380 | 0.395 | 0.415 |
| E1 | 6.22 | --- | --- | 0.245 | --- | --- |
| H1 | 6.10 | 6.30 | 6.50 | 0.240 | 0.248 | 0.256 |
| L | 12.27 | 12.82 | 14.27 | 0.483 | 0.505 | 0.562 |
| L1 | 2.47 | --- | 3.90 | 0.097 | --- | 0.154 |
| L2 | --- | --- | 16.70 | --- | --- | 0.657 |
| Q | 2.59 | 2.74 | 2.89 | 0.102 | 0.108 | 0.114 |
| φP | 3.50 | 3.84 | 3.89 | 0.138 | 0.151 | 0.153 |
| Q1 | 2.70 | --- | 2.90 | 0.106 | --- | 0.114 |

Flow (wave) soldering (solder dipping)

| Product | Peak Temperature | Dipping Time |
|----------------|------------------|--------------|
| Pb device | 245°C ±5°C | 5sec ±1 sec |
| Pb-Free device | 260°C +0/-5°C | 5sec ±1 sec |



This integrated circuit can be damaged by ESD. UniverChip Corporation recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedure can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Attention:

- Any and all XPX power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your XPX power representative nearest you before using any XPX power products described or contained herein in such applications.
- XPX power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all XPX power products described or contained herein.
- Specifications of any and all XPX power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- XPX power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all XPX power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of XPX power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. XPX power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/ technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the XPX power product that you intend to use.
- This catalog provides information as of Sep.2019. Specifications and information herein are subject to change without notice.